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Complete if Known 09/510375 **Application Number** February 22, 2000 Filing Date Williams, Brett **First Named Inventor** RECEIVED **Group Art Unit** 2187 Kim, Hong **Examiner Name** DEC 1 9 2002

Sheet 1 of 1

Attorney Docket No: 303.164US3

Technology Center 2 100

US PATENT DOCUMENTS										
Examiner Initial *	USP Document Number	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	Filing Date If Appropriate				
Alh	US-5,654,932	08/05/1997	Rao, G.R.M.	365	230.03	10/04/1995				

FOREIGN PATENT DOCUMENTS										
Examiner Initials*	Foreign Document No	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	T²				
ILL	WO-96/20482	07/04/1996	Zagar, P., et al	G11 C	7/00					

	OTHE	R DOCUMENTS NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²
ill		"Synchronous DRAM 2 MEG X 8 SDRAM", Micron Semiconductors, Inc., (1994),pp. 1-18	

**EXAMINER** 

DATE CONSIDERED